

Features

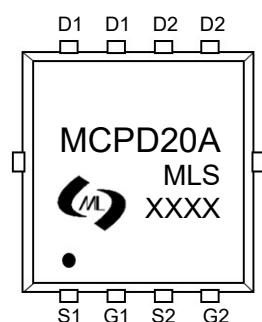
- High power and current handling capability
- Lead free product is acquired
- Surface mount package

Application

- Battery protection
- Load switch
- Power management

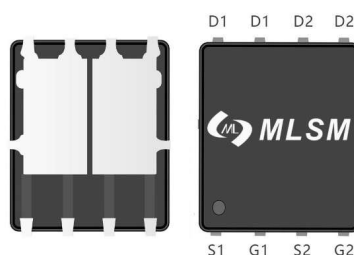
Product Summary

V_{DS}	$R_{DS(ON)}$ MAX	I_D MAX
30V	20mΩ@10V	20A
	30mΩ@4.5V	
-30V	45mΩ@-10V	-20A
	55mΩ@-4.5V	

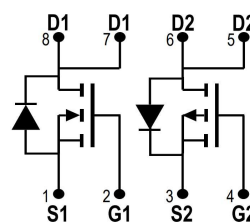


Marking and pin assignment

MCPD20A : Device code
XXXX : Code



PDFN5X6-8L view



Schematic diagram



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	N-Channel	P-Channel	Unit
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Common Ratings (TC=25°C Unless Otherwise Noted)

V_{DS}	Drain-Source Breakdown Voltage	30	-30	V
V_{GS}	Gate-Source Voltage	±20	±20	V
T_J	Maximum Junction Temperature	150	150	°C
T_{STG}	Storage Temperature Range	-55 to 150	-55 to 150	°C
I_S	Diode Continuous Forward Current	20	-20	A
	$T_C=25^\circ\text{C}$			

Mounted on Large Heat Sink

I_{DM}	Pulse Drain Current Tested	$T_C=25^\circ\text{C}$	100	-80	A
I_D	Continuous Drain Current	$T_C=25^\circ\text{C}$	20	-20	A
P_D	Maximum Power Dissipation	$T_C=25^\circ\text{C}$	30	25	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient		83.3	83.3	°C/W

Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MCPD20A	PDFN5X6-8L	MCPD20A	5,000	10,000	70,000	13"reel



N-Ch Electrical Characteristics (T _J =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
B _{V(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	30	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =30V, V _{GS} =0V	--	--	1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.0	1.5	2.5	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =20A	--	15	20	mΩ
		V _{GS} =4.5V, I _D =10A	--	20	30	mΩ
Dynamic Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
C _{ISS}	Input Capacitance	V _{DS} =15V, V _{GS} =0V, f=1MHz	--	572	--	pF
C _{OSS}	Output Capacitance		--	81	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	65	--	pF
Switching Characteristics						
Q _g	Total Gate Charge	V _{DS} =15V, I _D =12A, V _{GS} =10V	--	6.2	--	nC
Q _{gs}	Gate Source Charge		--	2.4	--	nC
Q _{gd}	Gate Drain Charge		--	2.5	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DD} =30V, I _D =10A, V _{GS} =10V, R _G =3Ω	--	3	--	nS
t _r	Turn-on Rise Time		--	7.5	--	nS
t _{d(off)}	Turn-Off Delay Time		--	20	--	nS
t _f	Turn-Off Fall Time		--	4	--	nS
Source- Drain Diode Characteristics						
V _{SD}	Forward on voltage	T _J =25°C, I _S =10A	--	--	1.2	V

P-CH Electrical Characteristics (TJ=25℃ unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ TJ = 25℃ (unless otherwise stated)						
BV(BR)DSS	Drain-Source Breakdown Voltage	VGS=0V, ID=-250μA	-30	--	--	V
IDSS	Zero Gate Voltage Drain Current	VDS=-30V, VGS=0V	--	--	-1	μA
IGSS	Gate-Body Leakage Current	VGS=±20V, VDS=0V	--	--	±100	nA
VGS(th)	Gate Threshold Voltage	VDS=VGS, ID=-250μA	-1.0	-1.5	-2.5	V
RDS(on)	Drain-Source On-State Resistance	VGS=-10V, ID=-20A	--	33	45	mΩ
		VGS=-4.5V, ID=-10A	--	40	55	mΩ
Dynamic Electrical Characteristics @ TJ = 25℃ (unless otherwise stated)						
Ciss	Input Capacitance	VDS=-15V, VGS=0V, f=1MHz	--	570	--	pF
Coss	Output Capacitance		--	80	--	pF
CRSS	Reverse Transfer Capacitance		--	70	--	pF
Switching Characteristics						
Qg	Total Gate Charge	VDS=-15V, ID=-10A, VGS=-10V	--	11.5	--	nC
Qgs	Gate Source Charge		--	2.3	--	nC
Qgd	Gate Drain Charge		--	2.1	--	nC
td(on)	Turn-on Delay Time	VDS=-15V, ID=-10A, VGS=-10V, RG=3Ω	--	3.8	--	nS
tr	Turn-on Rise Time		--	17.5	--	nS
td(off)	Turn-Off Delay Time		--	18	--	nS
tf	Turn-Off Fall Time		--	21.8	--	nS
Source- Drain Diode Characteristics						
VSD	Forward on voltage	TJ=25℃, IS=-10A	--	--	-1.2	V

N-Channel Typical Operating Characteristics

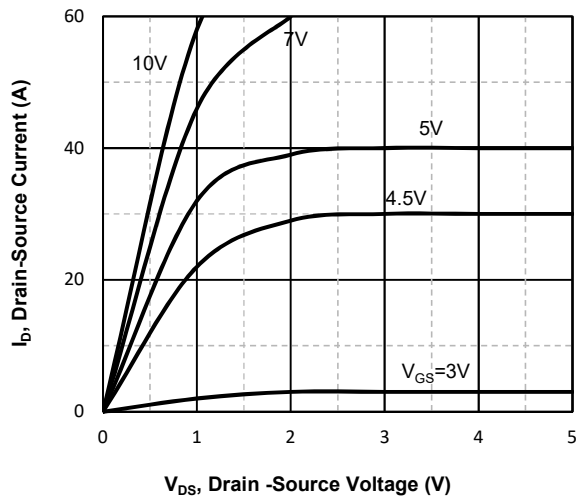


Fig1. Typical Output Characteristics

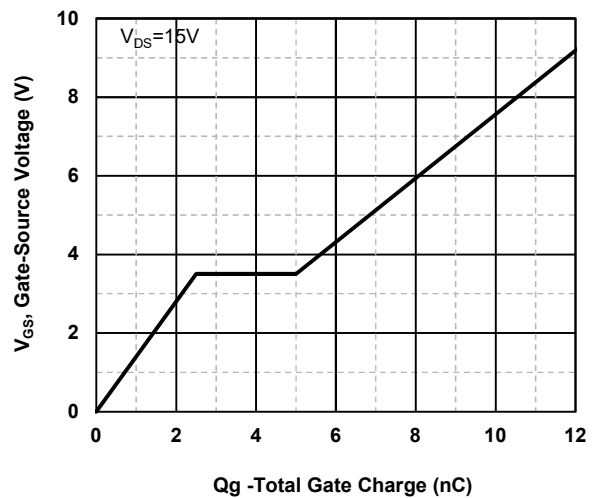


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

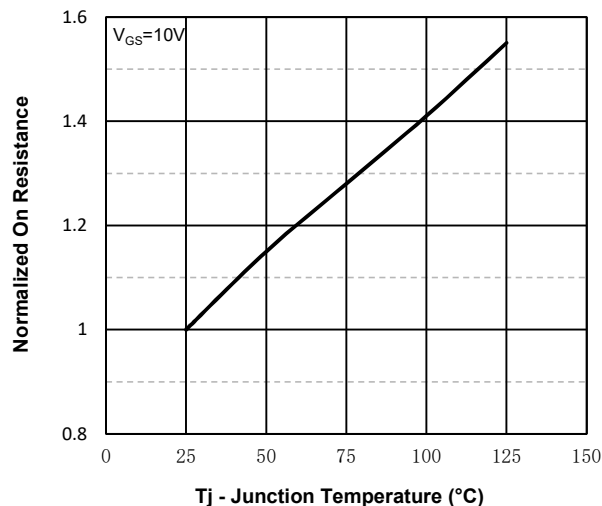


Fig3. Normalized On-Resistance Vs. Temperature

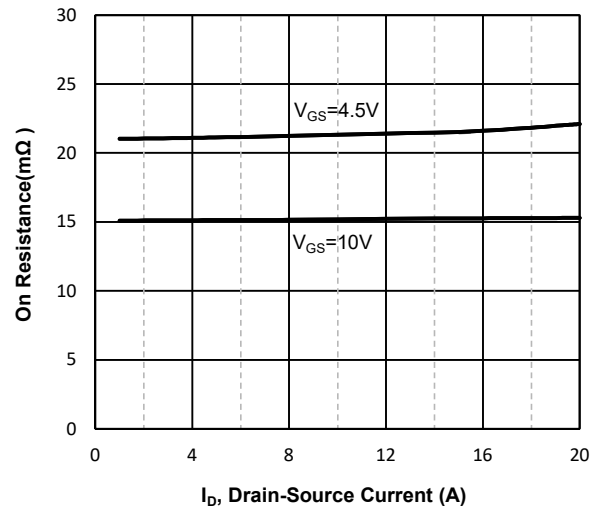


Fig4. On-Resistance Vs. Drain-Source Current

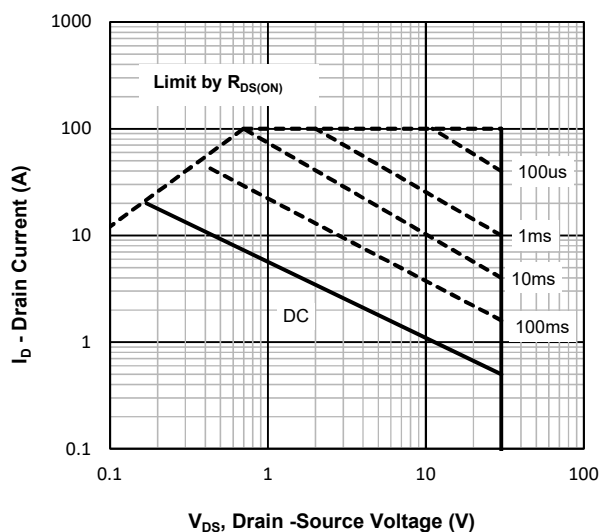


Fig5. Maximum Safe Operating Area

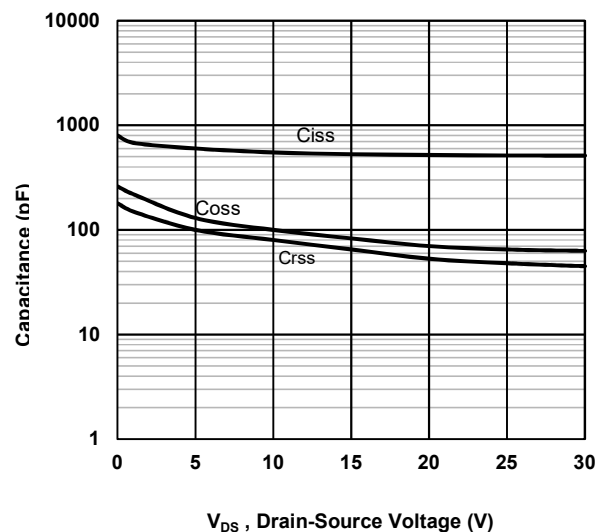
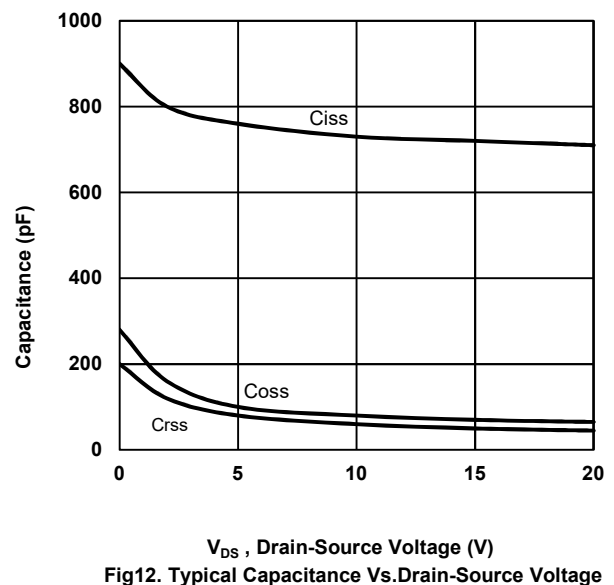
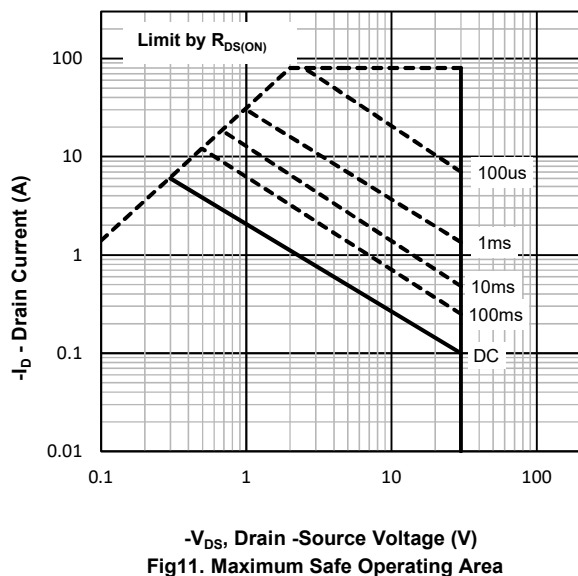
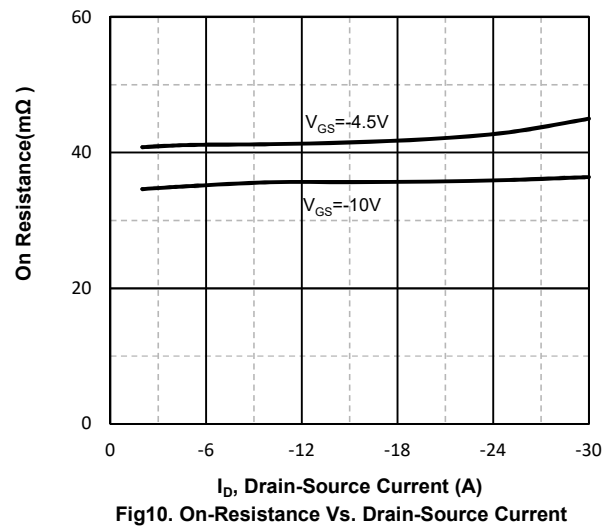
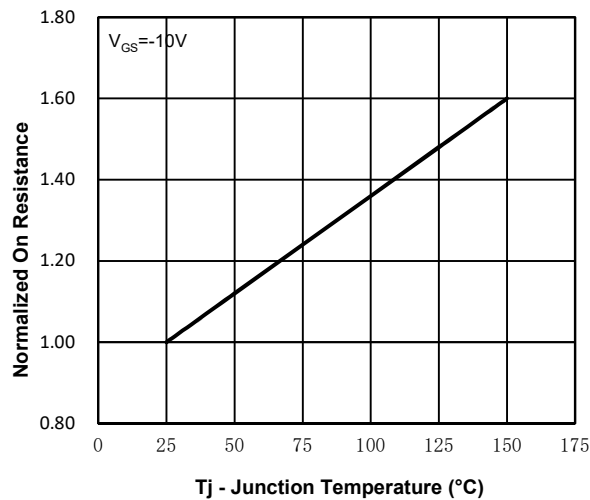
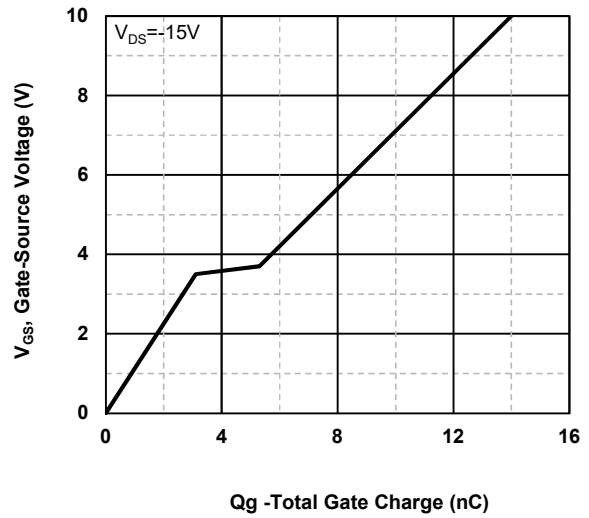
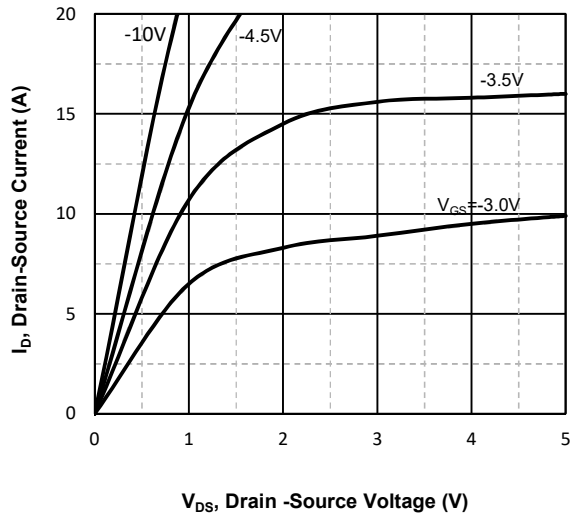
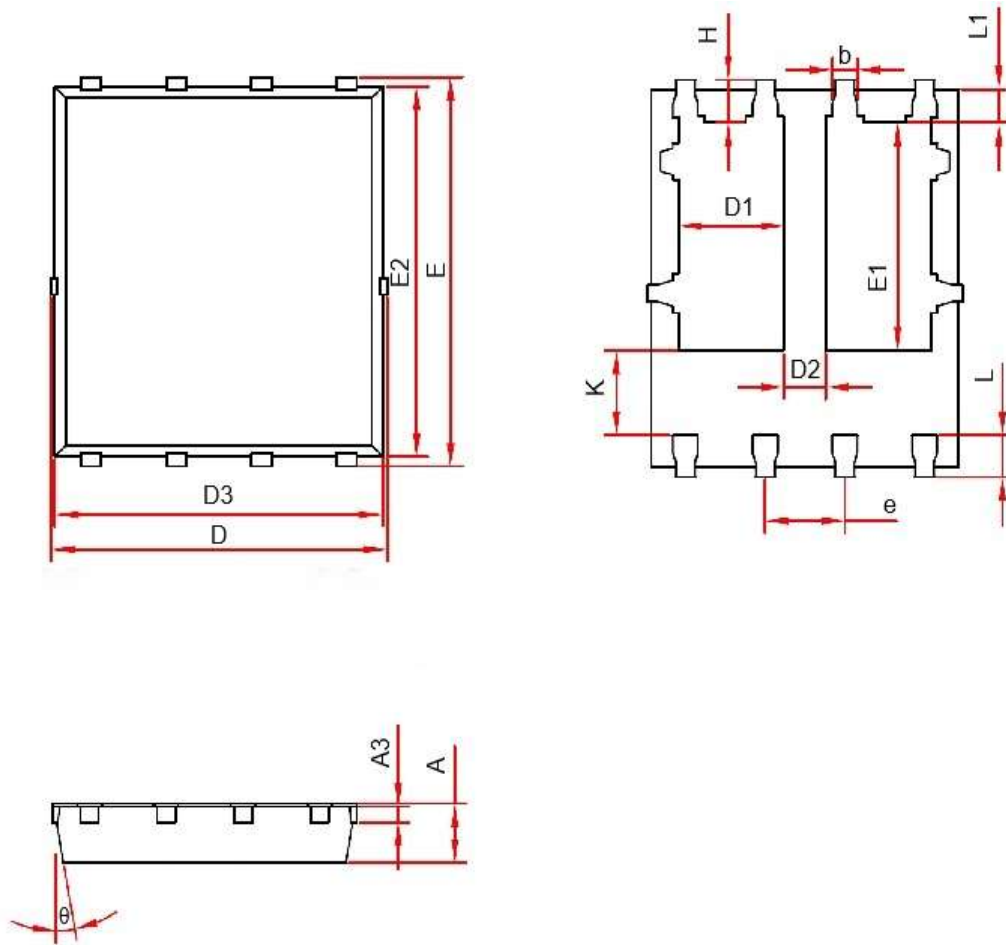


Fig6. Typical Capacitance Vs. Drain-Source Voltage

P-Channel Typical Operating Characteristics



PDFN5X6-8L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.950	1.050	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.950	5.050	0.196	0.200
E	5.950	6.050	0.235	0.239
D1	1.470	1.870	0.058	0.074
D2	0.470	0.870	0.019	0.034
E1	3.510	3.610	0.139	0.143
D3	4.850	4.950	0.192	0.196
E2	5.700	5.800	0.225	0.229
k	1.190	1.390	0.047	0.055
b	0.300	0.400	0.012	0.016
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
θ	10°	12°	10°	12°